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April 2013

FDP7N50

N-Channel UniFETTM MOSFET

500 V, 7 A, 900 mΩ

Features

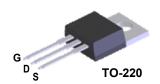
- Low Gate Charge (Typ. 12.8 nC)
- Low C_{rss} (Typ. 9 pF)
- · 100% Avalanche Tested

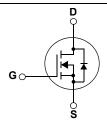
Applications

- ALCD/LED TV
- Lighting
- · Uninterruptible Power Supply
- · AC-DC Power Supplypplications

Description

UniFETTM MOSFET is Fairchild Semiconductor[®]'s high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.





Absolute Maximum Ratings

Symbol	Parameter		FDP7N50	Unit	
V _{DSS}	Drain-Source Voltage		500	V	
I _D	Drain Current	- Continuous (T _C = 25°C) - Continuous (T _C = 100°C)		7 4.2	A A
I _{DM}	Drain Current	- Pulsed	(Note 1)	28	A
V _{GSS}	Gate-Source voltage		±30	V	
E _{AS}	Single Pulsed Avalanche Energy		(Note 2)	270	mJ
I _{AR}	Avalanche Current		(Note 1)	7	А
E _{AR}	Repetitive Avalanche Energy		(Note 1)	8.9	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		(Note 3)	4.5	V/ns
P _D	Power Dissipation	(T _C = 25°C) - Derate above 25°C		89 0.71	W W/°C
T _{J,} T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C	
T _L	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds		300	°C	

Thermal Characteristics

Symbol	Parameter	FDP7N50	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max. 1.4		
$R_{\theta CS}$	Thermal Resistance, Case-to-Sink, Typ.	0.5	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP7N50	FDP7N50	TO-220		-	50

$\textbf{Electrical Characteristics} \quad \textbf{T}_{\text{C}} = 25^{\circ}\text{C unless otherwise noted}$

Symbol	Parameter	Conditions	Min.	Тур.	Max	Unit
Off Charac	Off Characteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0V, I _D = 250μA	500			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 250μA, Referenced to 25°C		0.5		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 500V, V _{GS} = 0V V _{DS} = 400V, T _C = 125°C			1 10	μ Α μ Α
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30V, V _{DS} = 0V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = -30V, V _{DS} = 0V			-100	nA
On Charac	teristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3.0		5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10V, I _D = 3.5A		0.76	0.9	Ω
9 _{FS}	Forward Transconductance	V _{DS} = 40V, I _D = 3.5A		2.5		S
Dynamic C	haracteristics	•		•		
C _{iss}	Input Capacitance	V _{DS} = 25V, V _{GS} = 0V,		720	940	pF
C _{oss}	Output Capacitance	f = 1.0MHz		95	190	pF
C _{rss}	Reverse Transfer Capacitance			9	13.5	pF
Switching	Characteristics					
t _{d(on)}	Turn-On Delay Time	$V_{DD} = 250V, I_{D} = 7A$	ı	6	20	ns
t _r	Turn-On Rise Time	$R_G = 25\Omega$	ı	55	120	ns
$t_{d(off)}$	Turn-Off Delay Time		ı	25	60	ns
t _f	Turn-Off Fall Time	(Note 4)		35	80	ns
Q_g	Total Gate Charge	V _{DS} = 400V, I _D = 7A	-	12.8	16.6	nC
Q_{gs}	Gate-Source Charge	V _{GS} = 10V	-	3.7		nC
Q_{gd}	Gate-Drain Charge	(Note 4)		5.8		nC
Drain-Sour	rce Diode Characteristics and Maximun	n Ratings		·		
I _S	Maximum Continuous Drain-Source Diode Forward Current				7	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				28	Α
V_{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0V, I _S = 7A			1.4	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0V, I _S = 7A		275		ns
Q _{rr}	Reverse Recovery Charge	dl _F /dt =100A/μs		1.7		μС

NOTES

 $^{{\}bf 1.}\ {\bf Repetitive}\ {\bf Rating:}\ {\bf Pulse}\ {\bf width}\ {\bf limited}\ {\bf by}\ {\bf maximum}\ {\bf junction}\ {\bf temperature}$

^{2.} I $_{AS}$ = 7A, V $_{DD}$ = 50V, L=10mH, R $_{G}$ = 25 Ω , Starting T $_{J}$ = 25 $^{\circ}$ C

^{3.} $I_{SD} \le 7 A$, di/dt $\le 200 A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting T_J = 25°C

^{4.} Essentially Independent of Operating Temperature Typical Characteristics

Typical Performance Characteristics

Figure 1. On-Region Characteristics

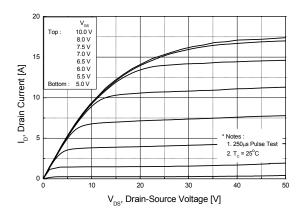


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

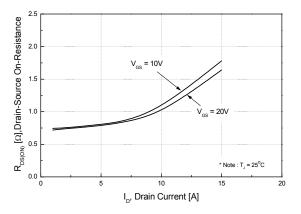


Figure 5. Capacitance Characteristics

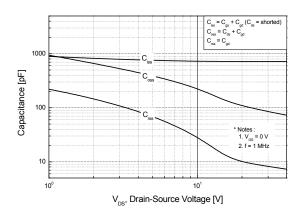


Figure 2. Transfer Characteristics

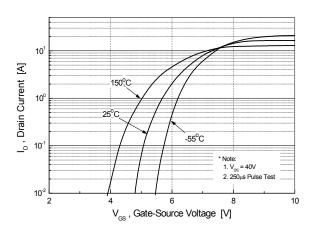


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

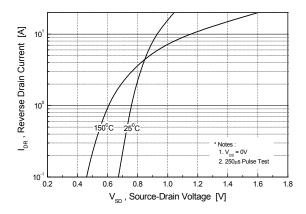
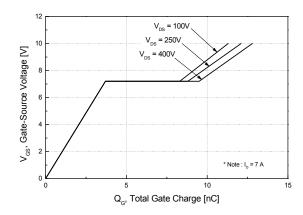


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

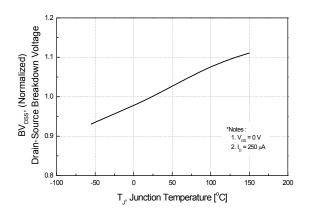


Figure 8. On-Resistance Variation vs. Temperature

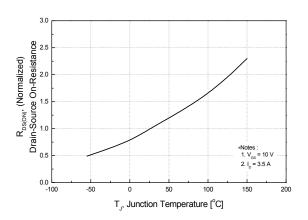


Figure 9. Maximum Safe Operating Area - FDP7N50

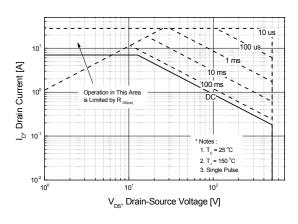


Figure 10. Maximum Drain Current vs. Case Temperature

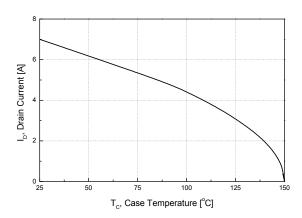
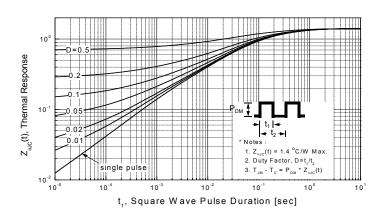
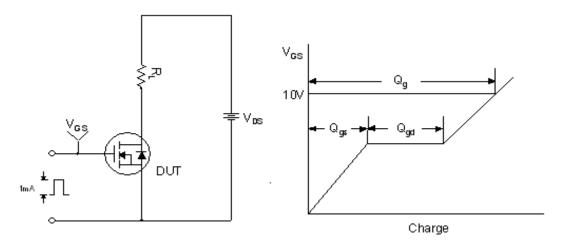


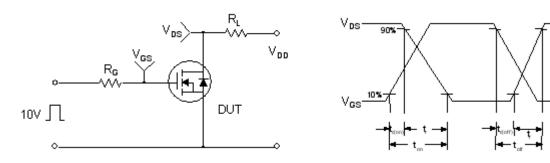
Figure 11. Transient Thermal Response Curve



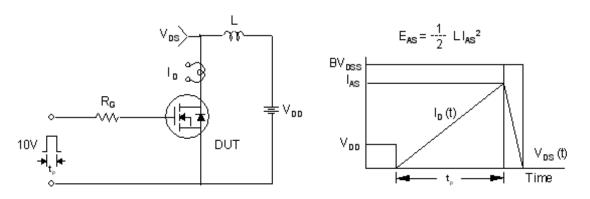
Gate Charge Test Circuit & Waveform



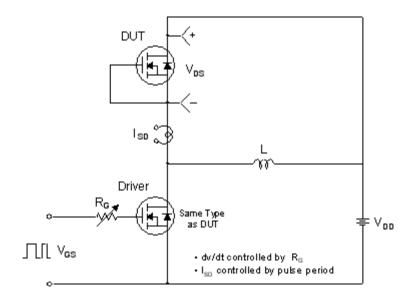
Resistive Switching Test Circuit & Waveforms

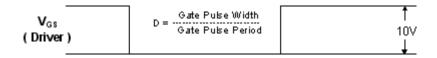


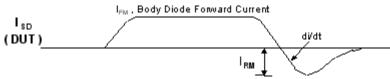
Unclamped Inductive Switching Test Circuit & Waveforms



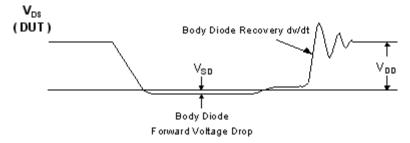
Peak Diode Recovery dv/dt Test Circuit & Waveforms





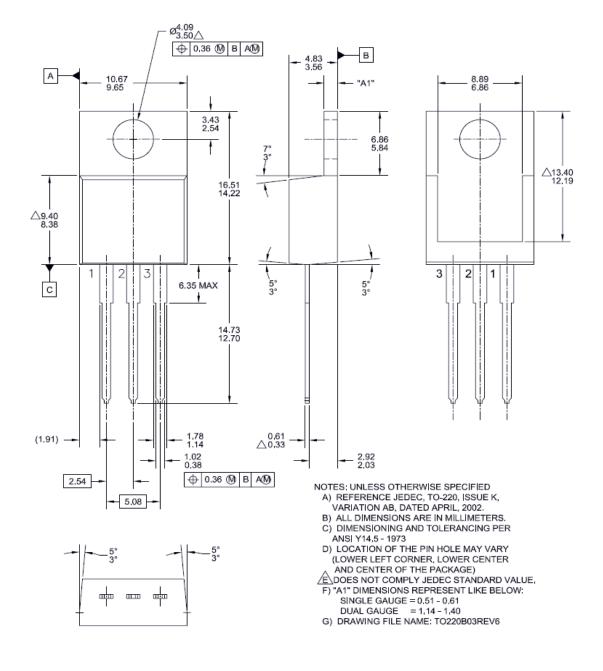


Body Diode Reverse Current



Mechanical Dimensions

TO-220B03







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